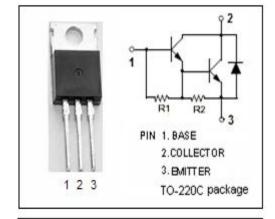


isc Silicon NPN Darlington Power Transistor

BD645

DESCRIPTION

- Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 60V(Min)
- · High DC Current Gain
 - : h_{FE}= 750(Min) @I_C= 3A
- Low Saturation Voltage
- Complement to Type BD646
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

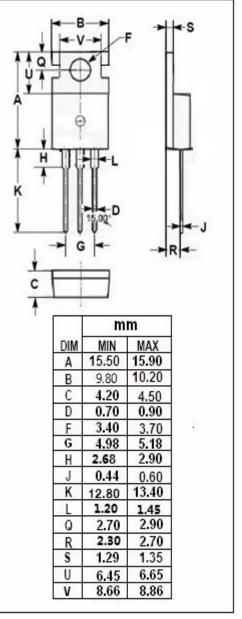
 Designed for use as complementary AF push-pull output stage applications

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	80	V	
VCEO	Collector-Emitter Voltage	60	V	
V _{EBO}	Emitter-Base Voltage	5	V	
Ic	Collector Current-Continuous	8	Α	
Іср	Collector Current-Peak	12	Α	
I _B	Base Current-Continuous	0.15	Α	
Pc	Collector Power Dissipation @ T _a =25°C	2	10/	
	Collector Power Dissipation @ T _C =25°C	62.5	W	
TJ	Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature Range	-65~150	$^{\circ}$	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance,Junction to Case	2	°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient	70	°C/W





isc Silicon NPN Darlington Power Transistor

BD645

ELECTRICAL CHARACTERISTICS

 T_{C} =25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CEO(SUS)}	Collector-Emitter Breakdown Voltage	I _C = 30mA; I _B = 0	60			V
V _{CE(sat)-1}	Collector-Emitter Saturation Voltage	Ic= 3A; I _в = 12mA			2.0	V
V _{CE(sat)-2}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 50mA			2.5	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 3A; V _{CE} = 3V			2.5	V
І _{сво}	Collector Cutoff Current	V _{CB} = 60V; I _E = 0			0.2	- mA
		V _{CB} = 40V; I _E = 0; T _C = 150°C			2.0	
I _{CEO}	Collector Cutoff Current	V _{CE} = 30V; I _B = 0			0.5	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			5	mA
h _{FE}	DC Current Gain	I _C = 3A; V _{CE} = 3V	750			

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